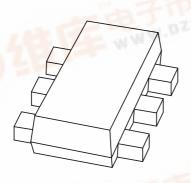
DISCRETE SEMICONDUCTORS

DATA SHEET



PMEG2005AEV; PMEG3005AEV; PMEG4005AEV

Very low V_F MEGA Schottky barrier rectifiers

Product specification

2003 Aug 20







PMEG2005AEV; PMEG3005AEV; PMEG4005AEV

FEATURES

- · Very low forward voltage
- · High surge current
- Ultra small plastic SMD package.

APPLICATIONS

- · Low voltage rectification
- High efficiency DC/DC conversion
- · Voltage clamping
- Inverse polarity protection
- Low power consumption applications.

DESCRIPTION

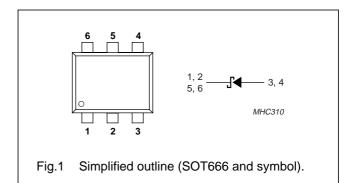
Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOT666 ultra small SMD plastic package.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
l _F	forward current	0.5	Α
V_R	reverse voltage		
	PMEG2005AEV	20	V
	PMEG3005AEV	30	٧
	PMEG4005AEV	40	V

PINNING

PIN	DESCRIPTION
1	cathode
2	cathode
3	anode
4	anode
5	cathode
6	cathode



MARKING

TYPE NUMBER	MARKING CODE
PMEG2005AEV	G1
PMEG3005AEV	G2
PMEG4005AEV	G3

RELATED PRODUCTS

TYPE NUMBER	DESCRIPTION	FEATURE
PMEGxx05AEA	0.5 A; 20/30/40 V very low V _F MEGA Schottky rectifier	SOD323 (SC-76) package
PMEG2005EB	0.5 A; 20 V very low V _F MEGA Schottky rectifier	SOD523 (SC-79) package
PMEG2010EA	1 A; 20 V very low V _F MEGA Schottky rectifier	higher forward current

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Philips Semiconductors Product specification

Very low V_F MEGA Schottky barrier rectifiers

PMEG2005AEV; PMEG3005AEV; PMEG4005AEV

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage				
	PMEG2005AEV		_	20	V
	PMEG3005AEV		_	30	V
	PMEG4005AEV		_	40	V
I _F	continuous forward current	note 1	_	0.5	А
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta \le 0.5; \ \text{note 2}$	_	3.5	А
I _{FSM}	non-repetitive peak forward current	t _p = 8 ms; square wave; note 2	_	10	А
Tj	junction temperature	note 3	_	150	°C
T _{amb}	operating ambient temperature	note 3	-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

Notes

- 1. Refer to SOT666 standard mounting conditions.
- 2. Only valid if pins 3 and 4 are connected in parallel.
- 3. For Schottky barrier diodes thermal runaway has to be considered, as in some applications, the reverse power losses (P_R) are a significant part of the total power losses. Nomograms for determination of the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	PARAMETER CONDITIONS			
R _{th j-a}	thermal resistance from junction to	in free air; notes 1 and 2	405	K/W	
	ambient	in free air; notes 2 and 3	215	K/W	
R _{th j-s}	thermal resistance from junction to soldering point	note 4	80	K/W	

Notes

- 1. Refer to SOT666 standard mounting conditions.
- For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses
 P_R are a significant part of the total power losses. Nomograms for determination of the reverse power losses P_R and
 I_{F(AV)} rating will be available on request.

3

- 3. Device mounted on an FR4 printed-circuit board with copper clad 10×10 mm.
- 4. Solder point of cathode tab.

2003 Aug 20

PMEG2005AEV; PMEG3005AEV; PMEG4005AEV

ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

CVMDOL	DADAMETED	CONDITIONS	PMEG2005AEV		PMEG3005AEV		PMEG4005AEV		UNIT
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	TYP.	MAX.	TYP.	MAX.	UNII
V _F	forward voltage	I _F = 0.1 mA	90	130	90	130	95	130	mV
		I _F = 1 mA	150	190	150	200	155	210	mV
		I _F = 10 mA	210	240	215	250	220	270	mV
		I _F = 100 mA	280	330	285	340	295	350	mV
	$I_{F} = 500 \text{ mA}$		355	390	380	430	420	470	mV
I _R	continuous reverse	V _R = 10 V; note 1	15	40	12	30	7	20	μΑ
	current	V _R = 20 V; note 1	40	200	_	_	_	_	μΑ
		V _R = 30 V; note 1	_	_	40	150	_	_	μΑ
		V _R = 40 V; note 1	_	_	_	_	30	100	μΑ
C _d	diode capacitance	V _R = 1 V; f = 1 MHz	66	80	55	70	43	50	pF

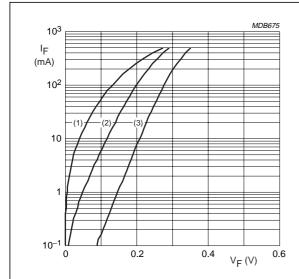
Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

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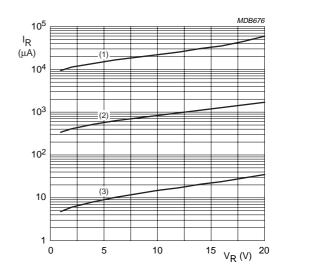
GRAPHICAL DATA



PMEG2005AEV

- (1) $T_{amb} = 150 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

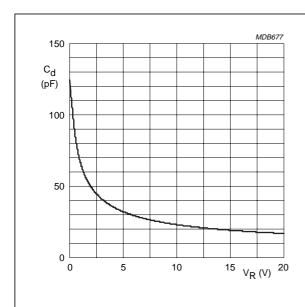
Fig.2 Forward current as a function of forward voltage; typical values.



PMEG2005AEV

- (1) $T_{amb} = 150 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.



PMEG2005AEV

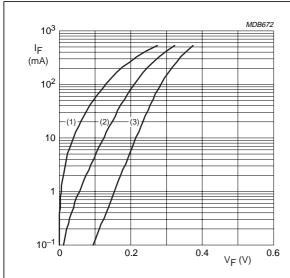
f = 1 MHz; $T_{amb} = 25 \,^{\circ}\text{C}$.

Fig.4 Diode capacitance as a function of reverse voltage; typical values.

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Very low V_F MEGA Schottky barrier rectifiers

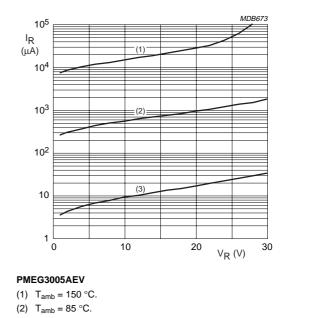
PMEG2005AEV; PMEG3005AEV; PMEG4005AEV



PMEG3005AEV

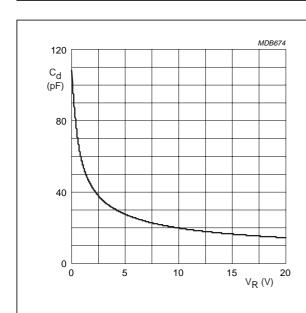
- (1) T_{amb} = 150 °C.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.5 Forward current as a function of forward voltage; typical values.



(3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.6 Reverse current as a function of reverse voltage; typical values.



PMEG3005AEV

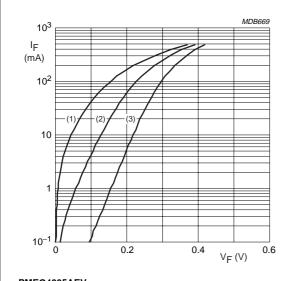
f = 1 MHz; T_{amb} = 25 °C.

Fig.7 Diode capacitance as a function of reverse voltage; typical values.

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Very low V_F MEGA Schottky barrier rectifiers

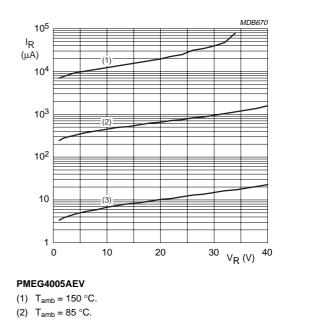
PMEG2005AEV; PMEG3005AEV; PMEG4005AEV



PMEG4005AEV

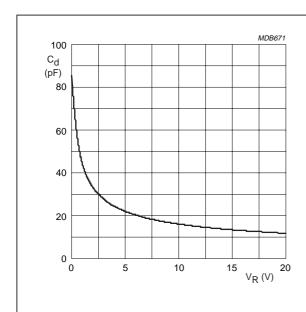
- (1) T_{amb} = 150 °C.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \,^{\circ}C$.

Fig.8 Forward current as a function of forward voltage; typical values.



- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.9 Reverse current as a function of reverse voltage; typical values.



PMEG4005AEV

f = 1 MHz; $T_{amb} = 25 \, ^{\circ}\text{C}$.

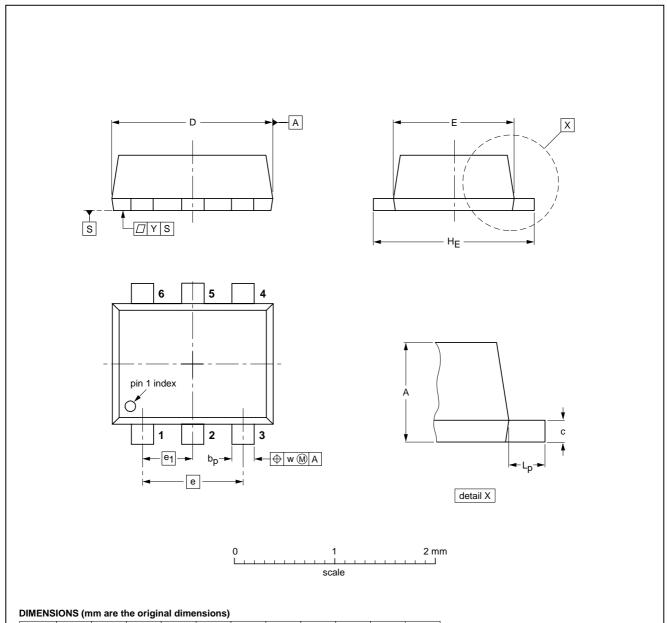
Fig.10 Diode capacitance as a function of reverse voltage; typical values.

PMEG2005AEV; PMEG3005AEV; PMEG4005AEV

PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



UNIT	A	bp	С	D	E	е	e ₁	HE	Lp	w	у
mm	0.6 0.5	0.27 0.17	0.18 0.08	1.7 1.5	1.3 1.1	1.0	0.5	1.7 1.5	0.3 0.1	0.1	0.1

OUTLINE		REFERENCES				ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT666						-01-01-04 01-08-27	

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Philips Semiconductors Product specification

Very low V_F MEGA Schottky barrier rectifiers

PMEG2005AEV; PMEG3005AEV; PMEG4005AEV

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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